

## LM96530 Ultrasound Transmit/Receive Switch

Check for Samples: LM96530

#### **FEATURES**

- 8-Channel High-Voltage Receive Side Switches without Charge-Injection
- Can be Used for Receive Protection and/or Receive Multiplexing with SPI<sup>™</sup> Compatible Bus Control
- Channel Bandwidth Supports 1MHz to 20MHz Transducers
- Input Accepts Pulses and Continuous-Wave Signals within ±60V
- Integrated Output Clamping Diodes Limit Output to ±0.7V
- Low Harmonic Distortion HD2 at -75dBc at 5MHz
- Continuous-Wave Operation
- Soft-Switcher Based on a Diode Bridge Architecture Yielding Better Noise Performance and Faster Turn-On and -Off Times than Competing T-Gate Switch Architectures
- 2.5V to 3.3V CMOS SPI<sup>™</sup> Compatible Logic Interface with Daisy Chain Capability
- Bias Current Source (I<sub>S</sub>) can be Scaled between 0 and 8mA via an External Resistor

### **DESCRIPTION**

The LM96530 is an eight-channel monolithic high-voltage, high-speed T/R (Transmit/Receive) switch for multi-channel medical ultrasound applications. It is well-suited for use with Texas Instrument's LM965XX series chipset which offers a complete medical ultrasound solution targeted towards low-power, portable systems.

The LM96530 contains eight high-voltage T/R switches with integrated clamping diodes. This chip protects the inputs of the receive channel's LNA (Low Noise Amplifier) from the high-voltage pulses of the transmit channel. Advanced features include a diode bridge with internal current sources that are programmable via an external resistor. Low-power operation is enabled via per-channel-selectable switching.

Texas Instruments also offers a development package for sale which includes a driver hardware and software package with a graphical user interface for configuration and monitoring.

### **APPLICATIONS**

Ultrasound Imaging

**Table 1. Key Specifications** 

	VALUE	UNIT
Input voltage	±60	V
Output voltage clamp ( I <sub>S</sub> = 1mA)	±0.7	V
On-resistance	18	Ω
Off-isolation at 5MHz	-58	dB
Noise spectral density at 5MHz	0.5	nV/√Hz
Harmonic distortion		
HD2	-75	dB
HD3	-75	dB
Channel crosstalk at 5MHz	-73	dB
Operating Temp.	0 to +70	°C

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### **Block Diagram**

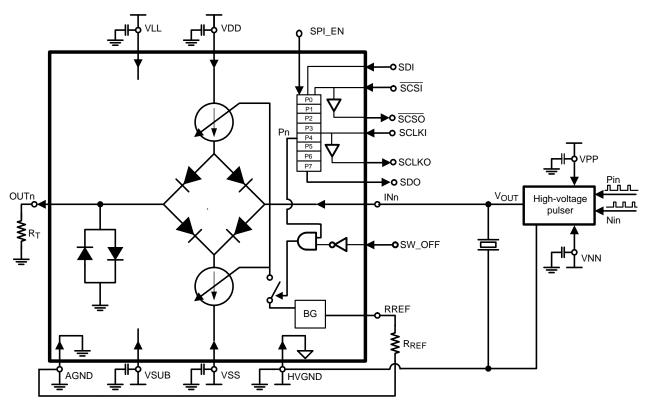


Figure 1.

# **Typical Application**

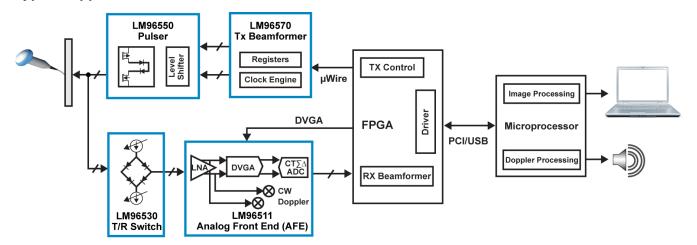


Figure 2. 8-Channel Transmit/Receive Chipset

Submit Documentation Feedback



### Pin Diagram

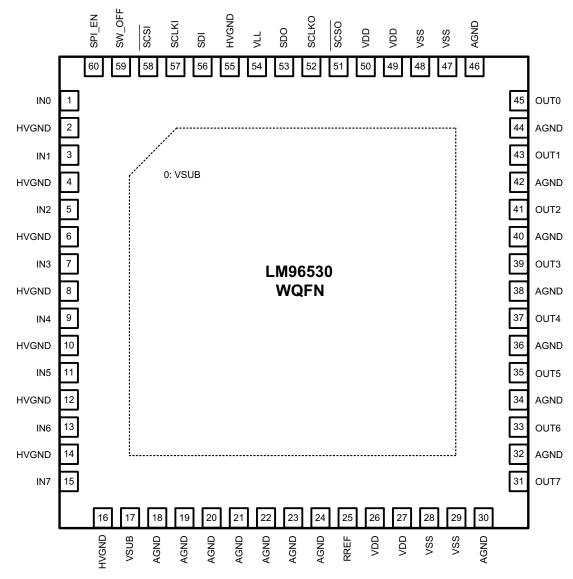


Figure 3. WQFN Package See Package Number NKA0060A

#### **PIN DESCRIPTIONS**

Pin No.	Name	Туре	Function and Connection
1, 3, 5, 7, 9, 11, 13, 15	INn n=0,,7	Input	High-voltage input
45, 43, 41, 39, 37, 35, 33, 31	OUTn n=0,	Output	Low-voltage output
25	RREF	Output	External resistor to AGND. Used to set internal current sources. $R_{REF} = 6.25 \text{ k}\Omega \rightarrow I_S = 8\text{mA};$ $R_{REF} = 12.5 \text{ k}\Omega \rightarrow I_S = 4\text{mA};$ $R_{REF} = 25 \text{ k}\Omega \rightarrow I_S = 2\text{mA};$ $R_{REF} = 50 \text{ k}\Omega \rightarrow I_S = 1\text{mA}$
59	SW_OFF	Input	1 = Switch all channels OFF 0 = Use SPI™ to control switch



#### PIN DESCRIPTIONS (continued)

Pin No.	Name	Туре	Function and Connection
60	SPI_EN	Input	1 = Enable the SPI™ Interface 0 = Disable the SPI™ Interface and presets SPI™ registers for all switches ON.
58	SCSI	Input	SPI™ chip select input, 0 = Chip Select
57	SCKI	Input	SPI™ compatible clock input
56	SDI	Input	SPI™ compatible data input
53	SDO	Output	SPI™ compatible data buffered output
52	SCKO	Output	SPI™ compatible clock buffered output
51	SCSO	Output	SPI™ chip select buffered output
26, 27, 49, 50	VDD	Power	Positive analog supply voltage (+5V)
28, 29, 47, 48	VSS	Power	Negative analog supply voltage (-5V)
54	VLL	Power	Logic voltage supply (+2.5 to 3.3V)
0, 17	VSUB	Power	Negative high voltage supply (-65V)
2, 4, 6, 8, 10, 12, 14, 16, 55	HVGND	Ground	High voltage reference potential (0V)
All others	AGND	Ground	Analog and logic low voltage reference input, logic ground (0V)



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **Absolute Maximum Ratings** (1)(2)

Maximum Junction Temperature (T <sub>JMAX</sub> )	+150°C
Storage Temperature Range	-40°C to +125°C
Supply Voltage (VDD)	+0.3V to +5.5V
Supply Voltage (VSS)	+0.3V and -5.5V
Supply Voltage (VSUB)	-70V (Must always be most negative voltage)
IO Supply Voltage (VLL)	-0.3V to +3.6V
Voltage at High Voltage Analog Inputs	-70V to 70V
Voltage at Logic Inputs (SCLKI, SDI SCSI, SW_OFF)	-0.3V to VLL+0.3v

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is specified to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

#### **Operating Ratings**

operating mating	J	
Operation Junction Tem	perature	0°C to + 70°C
VDD, -VSS, Analog Sup	oply	+4.7V to 5.3V
VLL, Logic Supply		+2.4V to 3.5V
High Voltage Analog Inp	puts	-60V to +60V, VSUB must be most negative supply
VSUB, Substrate bias su	upply	−50V to −65V
Package Thermal Resis	tance (θ <sub>JA</sub> )	20°C/W
ESD Tolerance	Human Body Model (1)	2kV
	Machine Model	150V
	Charge Device Model	750V

(1) The human body model is a 100pF capacitor discharged through a  $1.5k\Omega$  resistor into each pin.



#### **Analog Characteristics**

Unless otherwise stated, the following conditions apply.

 $VLL = +2.5V, \ VDD = -VSS = 5V, \ VSUB = -60V, \ R_{REF} = 50 \ k\Omega, \ R_T = 50\Omega, \ f_{IN} = 5 \ MHz, \ SW\_OFF = SPI\_EN = 0V, \ T_A = 25^{\circ}C.^{(1)}$ 

	Parameter	Test Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	High Voltage Analog Inputs	igh Voltage Analog Inputs			+60	V
e <sub>n</sub>	Voltage Noise	at 5MHz		0.8		nV/√Hz
BW	-3dB Bandwidth			150		MHz
HD2	Second harmonic distortion			-60		dBc
HD3	Third harmonic distortion	0.1V <sub>PP</sub> 5MHz tone applied as input		-65		dBc
X <sub>TALK</sub>	Channel crosstalk			-69		dB
T <sub>ON</sub>	Turn-on time			2		μs
T <sub>OFF</sub>	Turn-off time			0.2		μs
Iso_off	Off isolation	0.1Vpp 5MHz tone is applied as input		-55		dB
R <sub>ON</sub>	On resistance of TR switch			125		Ω
IL	Insertion Loss	f <sub>IN</sub> = 5MHz		-5.5		dB
V <sub>CLAMP</sub>	Output clamped voltage			±0.7		V
I <sub>MISMATCH</sub>	Current source mis-match			0.03	0.2	mA
VDD, VSS				14	20	mA
VLL	Power Supply Current			5		μΑ
VSUB				0.45		mA

<sup>(1)</sup> Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

Unless otherwise stated, the following conditions apply VLL = +2.5V, VDD =  $\neg$ VSS = 5V, VSUB =  $\neg$ 60V, R<sub>REF</sub> = 25 k $\Omega$ , R<sub>T</sub> = 50 $\Omega$ , f<sub>IN</sub> = 5MHz, SW\_OFF = SPI\_EN = 0V, T<sub>A</sub> = 25°C. (1)

	Parameter	Test Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	High Voltage Analog Inputs	VSUB must be most negative voltage. See (2)	-60		+60	V
e <sub>n</sub>	Voltage Noise	at 5MHz		0.7		nV/√Hz
BW	-3dB Bandwidth			150		MHz
HD2	Second harmonic distortion			-67		dBc
HD3	Third harmonic distortion	0.1V <sub>PP</sub> 5MHz tone applied as input		-70		dBc
X <sub>TALK</sub>	Channel crosstalk			-73		dB
T <sub>ON</sub>	Turn-on time			2		μs
T <sub>OFF</sub>	Turn-off time			0.2		μs
Iso_off	Off isolation	0.1Vpp 5MHz tone is applied as input		-58		dB
R <sub>ON</sub>	On resistance of TR switch			48		Ω
IL	Insertion Loss	f <sub>IN</sub> = 5MHz		-4		dB
V <sub>CLAMP</sub>	Output clamped voltage			±0.75		V
I <sub>MISMATCH</sub>	Current source mis-match			0.1	0.35	mA
VDD, VSS				23	30	mA
VLL	Power Supply Current			5		μA
VSUB				1		mA

<sup>(1)</sup> Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

<sup>(2)</sup> Total input signal levels, including any transient voltage overshoots, must be within this maximum voltage range.

<sup>(2)</sup> Total input signal levels, including any transient voltage overshoots, must be within this maximum voltage range.



Unless otherwise stated, the following conditions apply

# VLL = +2.5V, VDD = -VSS = 5V, VSUB = -60V, $R_{REF}$ = 12.5 k $\Omega$ , $R_{T}$ = 50 $\Omega$ , $f_{IN}$ = 5MHz, SW\_OFF = SPI\_EN = 0V, $T_{A}$ = 25°C. (1)

	Parameter	Test Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	High Voltage Analog Inputs	VSUB must be most negative voltage. See (2)	-60		+60	V
e <sub>n</sub>	Voltage Noise	at 5MHz		0.55		nV/√Hz
BW	-3dB Bandwidth			180		MHz
HD2	Second harmonic distortion			-73		dBc
HD3	Third harmonic distortion	0.1V <sub>PP</sub> 5MHz tone applied as input		-75		dBc
X <sub>TALK</sub>	Channel crosstalk			-73		dB
T <sub>ON</sub>	Turn-on time			2		μs
T <sub>OFF</sub>	Turn-off time			0.2		μs
Iso_off	Off isolation	0.1Vpp 5MHz tone is applied as input		-58		dB
R <sub>ON</sub>	On resistance of TR switch			27		Ω
IL	Insertion Loss	f <sub>IN</sub> = 5MHz		-3		dB
V <sub>CLAMP</sub>	Output clamped voltage			±0.78		V
I <sub>MISMATCH</sub>	Current source mis-match			0.25	0.6	mA
VDD, VSS				40	49	mA
VLL	Power Supply Current			5		μΑ
VSUB				2.2		mA

<sup>(1)</sup> Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

Unless otherwise stated, the following conditions apply

# VLL = +2.5V, VDD = -VSS = 5V, VSUB = -60V, $R_{REF}$ = 6.25 k $\Omega$ , $R_{T}$ = 50 $\Omega$ , $f_{IN}$ = 5MHz, SW\_OFF = SPI\_EN = 0V, $T_{A}$ = 25°C. (1)

	Parameter	Test Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	High Voltage Analog Inputs	VSUB must be most negative voltage. See <sup>(2)</sup>	-60		+60	V
e <sub>n</sub>	Voltage Noise	at 5MHz		0.5		nV/√Hz
BW	-3dB Bandwidth			180		MHz
HD2	Second harmonic distortion			-75		dBc
HD3	Third harmonic distortion	0.1V <sub>PP</sub> 5MHz tone applied to input		-75		dBc
X <sub>TALK</sub>	Channel crosstalk			-73		dB
T <sub>ON</sub>	Turn-on time			2		μs
T <sub>OFF</sub>	Turn-off time			0.2		μs
Iso_off	Off isolation	0.1Vpp 5MHz tone is applied as input		-58		dB
R <sub>ON</sub>	On resistance of TR switch			18		Ω
IL	Insertion Loss	f <sub>IN</sub> = 5MHz		-2.5		dB
V <sub>CLAMP</sub>	Output clamped voltage			±0.8		V
I <sub>MISMATCH</sub>	Current source mis-match			0.6	1.2	mA
VDD, VSS				75	86	mA
VLL	Power Supply Current			5		μA
VSUB				5		mA

<sup>(1)</sup> Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

<sup>(2)</sup> Total input signal levels, including any transient voltage overshoots, must be within this maximum voltage range.

<sup>(2)</sup> Total input signal levels, including any transient voltage overshoots, must be within this maximum voltage range.



### **Digital Characteristics**

Unless otherwise stated, the following conditions apply.

VLL = +2.5V, VDD = -VSS = 5V, VSUB = -60V,  $R_{REF}$  = 50 k $\Omega$ ,  $R_{T}$  = 50 $\Omega$ , SW\_OFF = 0V, SPI\_EN = 2.5V,  $T_{A}$  = 25°C. (1)

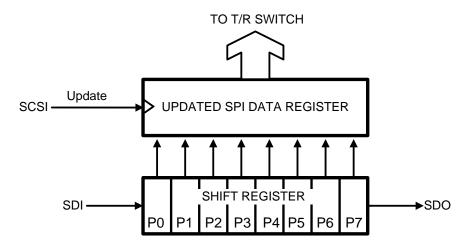
	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>IH</sub> Logical Input "HI" Voltage			2			V
V <sub>IL</sub>	Logical Input "LO" Voltage				0.5	V
I <sub>IN-H/L</sub>	Logic Input Current		-1	0.2	+1	μA
$V_{OH}$	Logical Output "HI" Voltage		2.2			V
V <sub>OL</sub>	Logical Output "LO" Voltage				0.3	V
t <sub>SSELS</sub>	SPI™ SCSI Setup Time		11			ns
t <sub>SSELH</sub>	SPI™ SCSI Hold Time		11			ns
t <sub>SSELHI</sub>	SPI™ SCSI HI Time			250		ns
t <sub>WS</sub>	SPI™ SDI Setup Time		11			ns
t <sub>WH</sub>	SPI™ SDI Hold Time		11			ns
t <sub>OD</sub>	SPI™ SCLKI to SDO Propagation Delay	C <sub>L</sub> = 5 pF			25	ns
t <sub>VALID</sub>	SPI™ SCSI to T/R Switch State Change Delay			30		ns
t <sub>SCLK</sub>	SPI™ SCLKI Period		100			ns
	SPI™ SCLKI Duty Cycle	See (2)	45		55	% of CLK Period
t <sub>SCLKOD-H</sub>	SPI™ SCLKI-HI to SCLKO- HI Propagation Delay				12	ns
t <sub>SCLKOD-L</sub>	SPI™ SCLKI-LO to SCLKO- LO Propagation Delay				12	ns
t <sub>SCSOD-H</sub>	SPI™ SCSI-HI to SCSO-HI Propagation Delay				12	ns
t <sub>SCSOD-L</sub>	SPI™ SCLSI-LO to SCLSO- LO Propagation Delay				12	ns
	Maximum Number of Daisy- Chained devices	SCLKI Freq. = 10MHz		16		

<sup>(1)</sup> Min and Max limits are 100% production tested at 25°C. Limits over the operating temperature range are specified through correlation using Statistical Quality Control (SQC) methods. Limits are used to calculate Average Outgoing Quality Level (AOQL).

<sup>(2)</sup> Specified by design.



# **SPI™ Timing**



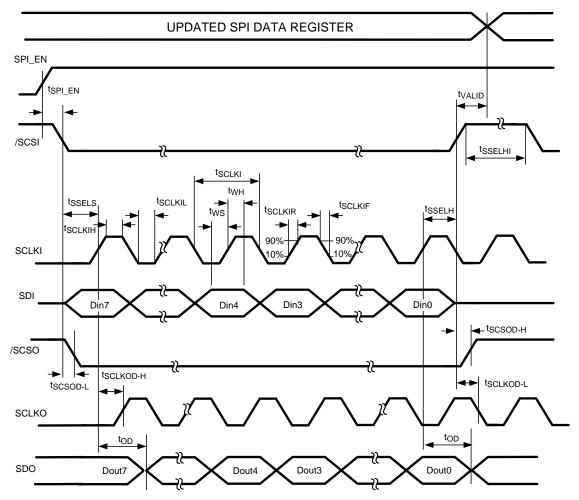
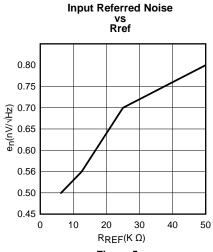


Figure 4. SPI™ Timing Diagram



## **Typical Performance Characteristics**

 $VLL = +2.5V, \ VDD = -VSS = 5V, \ VSUB = -60V, \ R_{REF} = 50 \ k\Omega, \ R_T = 50\Omega, \ f_{IN} = 5 \ MHz, \ T_A = 25^{\circ}C.$ 





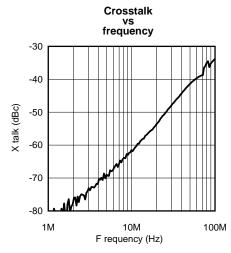
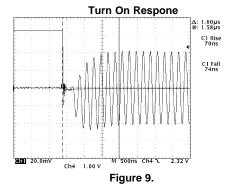
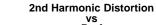


Figure 7.





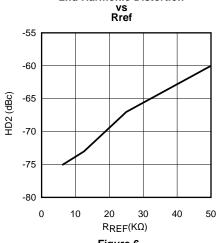


Figure 6.

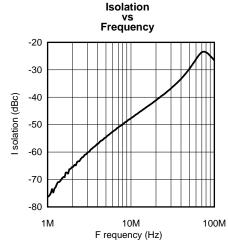


Figure 8.

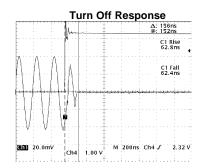


Figure 10.



#### **FUNCTIONAL DESCRIPTION**

The LM96530 RX switch provides an 8-channel receive side interface solution for medical ultrasound applications suitable for integration into multi-channel (128 / 256 channel) systems. Its diode-bridge-based architecture allows high-speed low-distortion channel designs targeting low-power, portable systems. A complete system can be designed using Texas Instruments' companion LM965XX chipset.

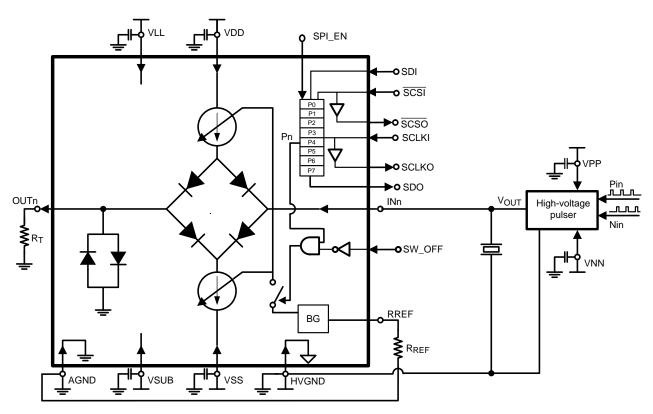


Figure 11. Block Diagram of T/R Channel

A functional block diagram of the IC is shown in Figure 11. Each RX switch channel on the IC has a high-voltage input that can be directly connected to a transducer driven by a high-voltage pulser, such as the LM96550. The input feeds into a diode bridge with its output being diode-clamped to  $\pm$  0.7V. The diode bridge bias current is set to 1 mA with Rref =  $50 \text{K}\Omega$ . Therefore, the output can be directly connected to a low noise amplifier (LNA) stage which must be protected from the high-voltage signals on the transducer.

The bias current of the bridge is determined by two equally-sized current sources with their current value ranging between 0 and 8mA depending on the external resistor Rref at the input of the bandgap reference block. While the bias current is the same value for all channels on the IC, each channel can be switched on and off individually with an 8-bit shift register that is programmed via a SPI<sup>TM</sup> compatible bus.

The on-chip analog circuitry requires dual 5V supplies VDD and VSS, a single logic supply VLL, and a high voltage negative bias, VSUB.

#### **SERIAL INTERFACE OPERATION**

The digital interface is comprised of an 8-bit shift register and a latch. Each bit controls one T/R switch channel, where the MSB bit, i.e., the first bit written (D7) controls channel 7, and the LSB bit (D0) controls channel 0. The three input pins, SDI, SCSI and SCKI, are all Schmitt Trigger inputs with 0.5V typical hysteresis. The output pins SDO, SCSO, and SCLKO are SPI™ compatible. The serial data input SDI is synchronously read into the shift register on the rising edge of the clock SCKI. When SCSI changes from low to high, the data in the shift register is transferred to the latch circuit, and output on the parallel data signals P0 through P7 which drive the switched bias current sources for channels n=0,..., 7, respectively. When SCSI changes from high to low, the latch output Pn, and thus the biasing condition, does not change.



#### DAISY CHAINING MULTIPLE LM96530 ICs

For connecting multiple T/R switch ICs, the LM965XX SPI<sup>TM</sup>-compatible bus can be daisy-chained up to 16 ICs at 10MHz SCLKI for easy PCB routing. The inputs SDI, SCSI and SCLKI are daisy-chained together with SDO, SCSO and SCLKO. Therefore, the next IC's SDI is connected to the previous IC's SDO. Similarly, the next IC's SCSI is connected to the previous IC's SCSO, and the next IC's SCLKI is connected to the previous IC's SCLKO, as shown in Figure 12. Daisy-chaining multiple LM96530 devices amounts to one large shift register with the number of bits being equal to 8 times the number of LM96530 ICs. For example, if 3 LM96530 ICs are daisy-chained, one can picture a 24-bit shift register. Thus, the MSB or first bit written on the SDI line (D23) will control channel 7 of the last LM96530, i.e., the IC that is daisy-chained the farthest away from the SPI master. The LSB or last bit written on the SDI line (D0) will control channel 0 of the first LM96530, i.e., the IC that is closest to the SPI master. It is important to note that If only one particular channel of an IC in the daisy-chain requires updating, all of the ICs, i.e., the entire shift register, must be written to.

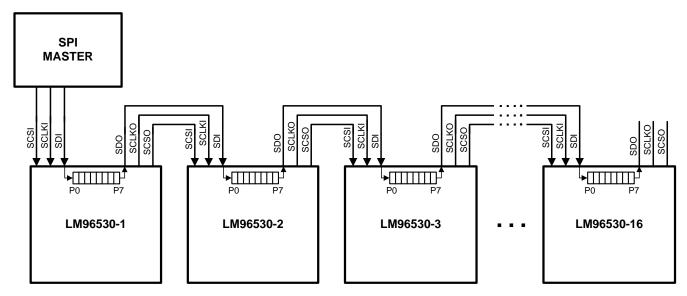


Figure 12. 16 LM96530 Devices Daisy Chained at SCLKI = 16MHz

#### **BASIC OPERATION WITHOUT SERIAL INTERFACE COMMUNICATION**

To disable the SPI™ compatible interface, connect the pin SPI\_EN to AGND. To reverse bias all 8 channels of the T/R switch, connect the pin, SW\_OFF to VLL. To forward bias all 8 channels of the T/R switch, connect the pin, SW\_OFF to AGND.

#### POWER-UP AND POWER-DOWN SEQUENCES

VSUB needs to always be the most negative supply – equal to or more negative than VSS or the most negative transmit pulse at all times. The power sequence should be to applied to VSUB first, followed by the remaining supplies in any order.

### SNAS499F - AUGUST 2010-REVISED MAY 2013



## **REVISION HISTORY**

Changes from Revision E (May 2013) to Revision F						
•	Changed layout of National Data Sheet to TI format		11			

Submit Documentation Feedback



## PACKAGE OPTION ADDENDUM

5-Nov-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package	Pins Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing	Qty	(2)	(6)	(3)		(4/5)	
LM96530SQ/NOPB	OBSOLETE	WQFN	NKA	60	TBD	Call TI	Call TI	0 to 70	LM96530SQ	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

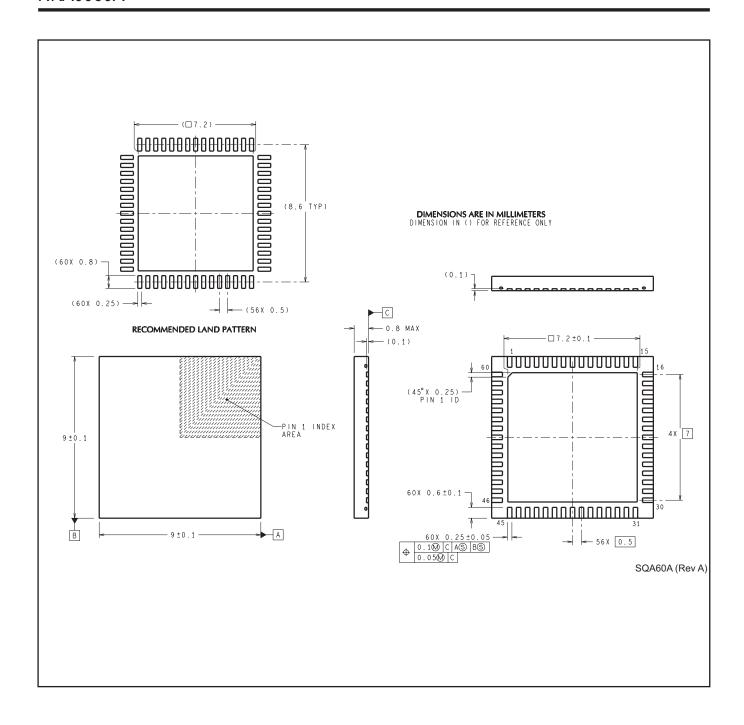
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





#### **IMPORTANT NOTICE**

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.